

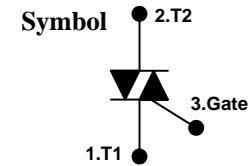
## HTP20-600

600V 20A TRIAC

$V_{DRM}$  = 600 V  
 $I_{T(RMS)}$  = 20A

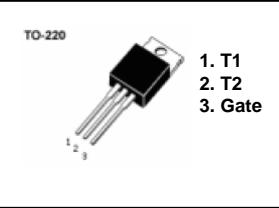
### FEATURES

- Repetitive Peak Off-State Voltage: 600V
- R.M.S On-state Current ( $I_{T(RMS)}=20A$ )
- High Commutation dv/dt



### General Description

The TRIAC HTP20-600 is suitable for AC switching application, phase control application such as heater control, motor control, lighting control, and static switching relay.



### Absolute Maximum Ratings $(Ta=25^{\circ}\text{C})$

Symbol	Parameter	Value	Units
$V_{DRM}$	Repetitive Peak Off-State Voltage	600	V
$I_{T(RMS)}$	R.M.S On-State Current ( $T_a = 90^{\circ}\text{C}$ )	20	A
$I_{TSM}$	Surge On-State Current (One Cycle, 50/60Hz, Peak, Non Repetitive)	50Hz	A
		60Hz	A
$V_{GM}$	Peak Gate Voltage	10	V
$I_{GM}$	Peak Gate Current	2	A
$P_{GM}$	Peak Gate Power Dissipation	5	W
$T_{STG}$	Storage Temperature Range	-40 to +125	°C
$T_j$	Operating Temperature	-40 to +125	°C

**Electrical Characteristics (T<sub>a</sub>=25°C)**

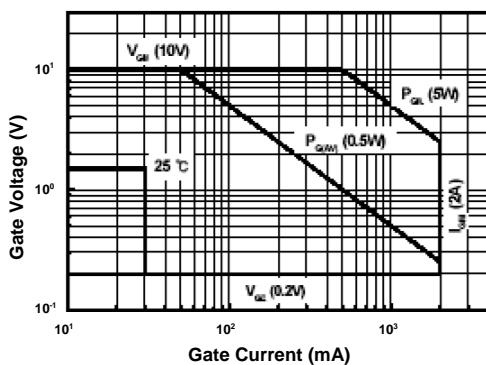
<b>Symbol</b>	<b>Parameter</b>	<b>Test Conditions</b>		<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Units</b>
I <sub>GT</sub>	Gate Trigger Current	V <sub>D</sub> =6V, R <sub>L</sub> =10Ω	1+, 1-, 3-			30	mA
V <sub>GT</sub>	Gate Trigger Voltage	V <sub>D</sub> =6V, R <sub>L</sub> =10Ω	1+, 1-, 3-			1.5	V
V <sub>GD</sub>	Non Trigger Gate Voltage	T <sub>j</sub> =125°C, V <sub>D</sub> =1/2V <sub>DRM</sub>		0.2			V
(dv/dt) <sub>C</sub>	Critical Rate of Rise of Off-State Voltage at Communication	T <sub>j</sub> =125°C, V <sub>D</sub> =2/3V <sub>DRM</sub> (di/dt) <sub>C</sub> =-10A/ms		8.0			V/uS
I <sub>H</sub>	Holding Current				25		mA
I <sub>DRM</sub>	Repetitive Peak Off-State Current	V <sub>D</sub> =V <sub>DRM</sub> , Single Phase, Half Wave, T <sub>j</sub> =125°C				2.0	mA
V <sub>TM</sub>	Peak On-State Voltage	I <sub>T</sub> =6A, Inst, Measurement				1.4	V

**Thermal Characteristics**

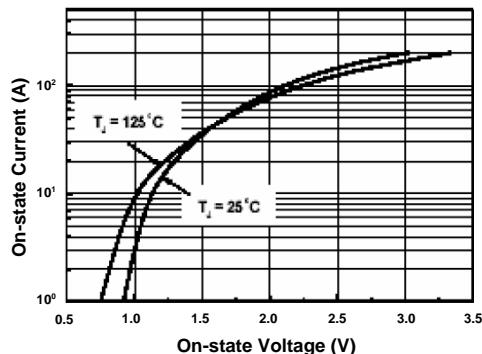
<b>Symbol</b>	<b>Parameter</b>	<b>Test Conditions</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Units</b>
R <sub>TH(J-C)</sub>	Thermal Resistance	Junction to Case			1.4	°C/W

## Performance Curves

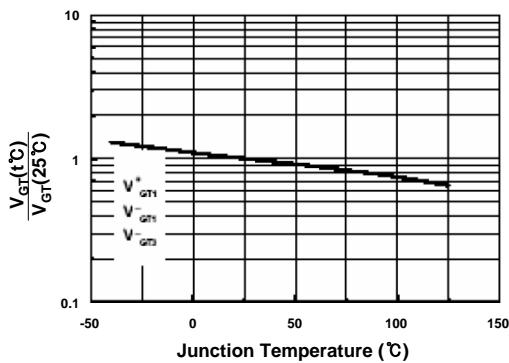
**Fig 1. Gate Characteristics**



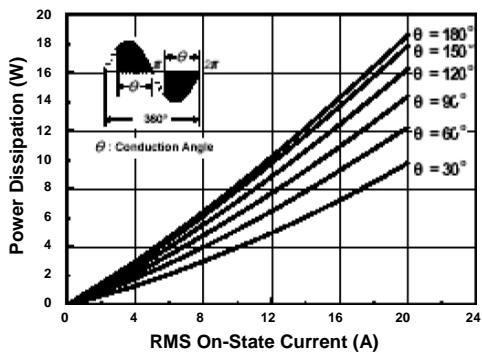
**Fig 2. On-State Voltage**



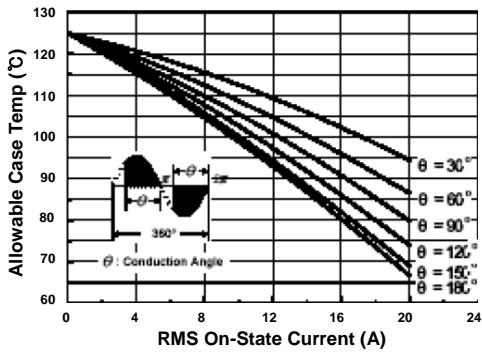
**Fig 3. Gate Trigger Voltage vs. Junction Temperature**



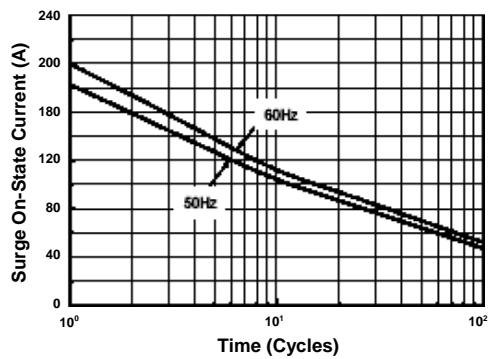
**Fig 4. On State Current vs. Maximum Power Dissipation**



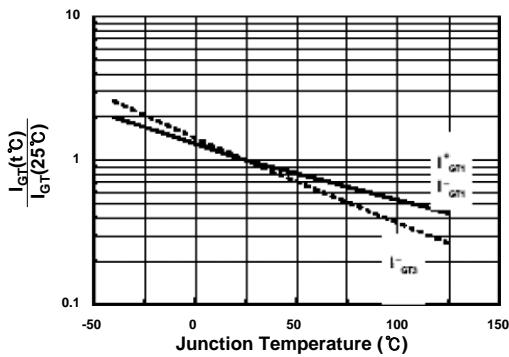
**Fig 5. On State Current vs. Allowable Case Temperature**



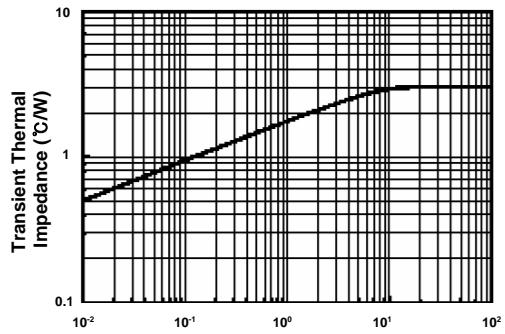
**Fig 6. Surge On-State Current Rating (Non-Repetitive)**



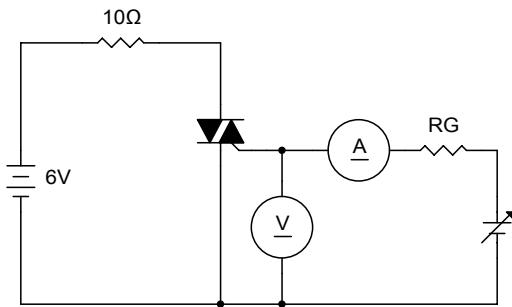
**Fig 7. Gate Trigger Current vs. Junction Temperature**



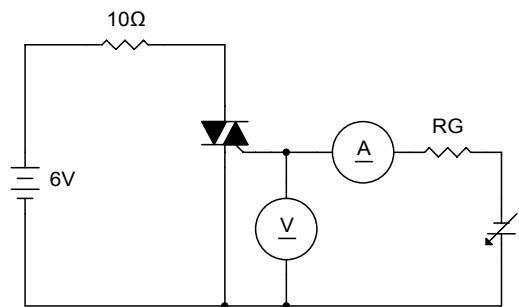
**Fig8. Transient Thermal Impedance**



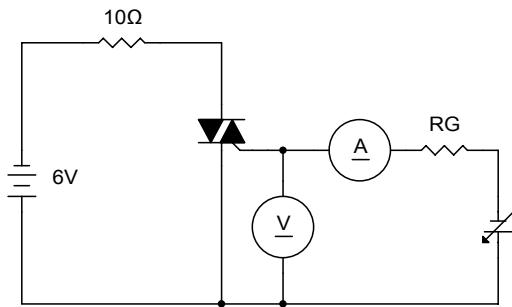
**Fig 7. Gate Trigger Characteristics Test Circuit**



Test Procedure I



Test Procedure II



Test Procedure III

## Package Dimension

HTP20-600  
(TO-220)